

Code No.: 3123

12. a) Explain the dest DIRBARING OF ENGINEERING test and expression for rise

B.E. 4/4 (E&EE/Inst/ECE) I Semester (Main) Examination, December 2010

VLSI DESIGN (Elective – I)

b) How do you design NA [Max. Marks: 75 Time: 3 Hours Note: 1) Answer all questions from Part 13. a) Explain with relevant dias 2) Answer any five questions from I Marks) 1. What are simulators? Mention any two types. 2. Realize a 2 input NAND gate in VLSI circuits. 3 3. Compare the gm of bipolar and CMOS transistor. 4. Explain why CMOS gates are called NOT based logic gates. 5. Draw the diagram of a CMOS current mirror. 6. Draw the circuit of a latch (D) based on cross coupled NOR gates. Realize the same using CMOS logic and explain. 3 7. What is photoresist and what is its importance in VLSI processing? 3 8. Explain the terms "setup time" and "hold time" in relation to a CMOS D register. 3 9. Explain what is meant by universal shift register. 2 10. Explain what do you understand by pseudo NMOS logic. 3 (50 Marks) PART - B 11. a) What are the different pull-up structures used in MOS based inverters? What are the relative advantages and disadvantages of each of these structures? 8

b) Which of the above structures has the fastest response?



12. a)	Explain the design of CMOS converter. Derive the relevant expression for rise time and fall time.
(d	How do you design NAND and NOR gates? Draw the circuit and layout diagrams.
13. a)	Explain with relevant diagrams, the steps involved in CMOS P-well fabrication process.
b)	Explain the process of photo lithography in IC fabrication.
14. a)	Explain the operation of a SRAM memory.
b)	Write about chemical vapour deposition.
15. a)	Design 8 to 1 MUX using pass transistor logic and explain.
b)	Write about etching Realize a 2 input NAND gate in VLSI circuits.
c)	3. Compare the gm of bipolar and CMOS mansistor noitabixo tuoda atirW
16. a)	Derive an expression for O/P voltage for an adder circuit, with a current mirror used to supply the bias current.
b)	Give the design rules for CMOS.
17. W	rite short notes on:
a)	Counter shift registers and an analogue at a state of the
b)	Design latchers design latcher design latchers design latchers design latchers design latcher d
c)	Optical lithography.